TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

# **TLP665J(S)**

## OFFICE MACHINE HOUSEHOLD USE EQUIPMENT TRIAC DRIVERSOLID STATE RELAY

TOSHIBA TLP665J(S) consists of a photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

- Peak Off-State Voltage •
- Trigger LED Current **On-State** Current
- : 600V(Min) : 10mA(Max)

: UL1577, File No.E67349

: SS EN60065, File No.9841102

SS EN60950, File No.9841102

: BS EN60065, File No.8385

- : 100 mA(Max)
- : 5000Vrms(Min) **Isolation Voltage**
- UL Recognized •

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- SEMKO Approved .
- **BSI** Approved •
- BS EN60950, File No.8386 Option(D4)type : DIN VDE0884 VDE Approved Certificate No.101399 Maximum Operating Insulation Voltage : 890VPK Highest Permissible Over Voltage :8000 VPK

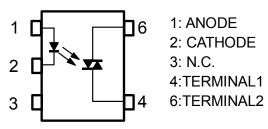
# (Note)When a VDE0884 approved type is needed,

#### please designate the "Option(D4)"

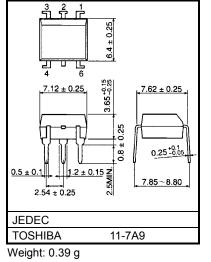
#### Construction Mechanical Rating

|                      | 7.62 mm pich<br>standard type | 10.16 mm pich<br>TLPXXXF type |
|----------------------|-------------------------------|-------------------------------|
| Creepage Distance    | 7.0 mm (Min)                  | 8.0 mm (Min)                  |
| Clearance            | 7.0 mm (Min)                  | 8.0 mm (Min)                  |
| Insulation Thickness | 0.5 mm (Min)                  | 0.5 mm (Min)                  |

## **PIN CONFIGURATION (TOP VIEW)**







<sup>2002-05-24</sup> 

### MAXIMUM RATINGS(Ta=25°C)

|          | CHARACTERISTIC                                   | SYMBOL                   | RATING              | UNIT                     |      |  |
|----------|--|--------------------------|---------------------|--------------------------|------|--|
|          | Forward Current                                  | ١ <sub>F</sub>           | I <sub>F</sub> 50   |                          |      |  |
| Q        | Forward Current Derating (Ta≥53°C)               |                          | ∆I <sub>F</sub> /°C | ∆I <sub>F</sub> /°C −0.7 |      |  |
| LED      | Peak Forward Current (100µs pulse, 100pps)       |                          | I <sub>FP</sub>     | 1                        | А    |  |
|          | Reverse Voltage                                  | V <sub>R</sub>           | 5                   | V                        |      |  |
|          | Off-State Output Terminal Voltage                | V <sub>DRM</sub>         | 600                 | V                        |      |  |
|          | On-State RMS Current                             | Ta=25°C                  | I <sub>T(RMS)</sub> | 100                      | mA   |  |
| ЯO       |  | Ta=70°C                  | II (RMS)            | 50                       |      |  |
| DETECTOR | On-State Current Derating (Ta≥25°C)              | $\Delta I_T / ^{\circ}C$ | -1.1                | mA /°C                   |      |  |
| DEJ      | Peak On-State Current (100µs pulse, 120pps)      | (100µs pulse, 120pps)    |                     |                          | А    |  |
|          | Peak Nonrepetitive Surge Current (Pw=10ms,DC=10  | I <sub>TSM</sub>         | 1.2                 | А                        |      |  |
|          | Junction Temperature                             | Tj                       | 115                 | °C                       |      |  |
| Оре      | rating Temperature Range                         | T <sub>opr</sub>         | -40~100             | °C                       |      |  |
| Stor     | age Temperature Range                            | T <sub>stg</sub>         | -55~125             | °C                       |      |  |
| Lea      | d Soldering Temperature (10s)                    | T <sub>sol</sub>         | 260                 | °C                       |      |  |
| Isol     | Isolation Voltage (AC,1min. , R.H.≤60%) (Note 2) |                          |                     | 5000                     | Vrms |  |

(Note 2)Pins1,2 and 3 shorted together and pin4 and pin6 shorted together.

#### **RECOMMENDED OPERATING CONDITIONS**

| CHARACTERISTIC        | SYMBOL           | MIN. | TYP. | MAX. | UNIT            |
|-----------------------|------------------|------|------|------|-----------------|
| Supply Voltage        | V <sub>AC</sub>  | _    | —    | 240  | V <sub>ac</sub> |
| Forward Current       | I <sub>F</sub>   | 15   | 20   | 25   | mA              |
| Peak On-State Current | I <sub>TP</sub>  | _    | —    | 1    | А               |
| Operating Temperature | T <sub>opr</sub> | -25  | _    | 85   | °C              |

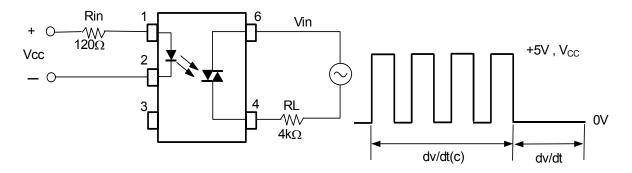
## ELECTRICAL CHARACTERISTICS(Ta=25°C)

| CHARACTERISTIC SYMBOL |   | TEST CONDITION   | MIN.                          | TYP. | MAX. | UNIT |      |
|-----------------------|---|------------------|-------------------------------|------|------|------|------|
|                       | Forward Voltage                                 | VF               | I <sub>F</sub> = 10 mA        | 1.0  | 1.15 | 1.3  | V    |
| LED                   | Reverse Current                                 | I <sub>R</sub>   | V <sub>R</sub> = 5 V          | —    | _    | 10   | μA   |
|                       | Capacitance                                     | CT               | V = 0, f=1MHz                 | _    | 30   | _    | pF   |
| Ц                     | Peak Off-State Current                          | I <sub>DRM</sub> | V <sub>DRM</sub> =600V        | —    | 10   | 1000 | nA   |
| 0<br>⊢                | Peak On-State Voltage                           | $V_{\text{TM}}$  | I <sub>TM</sub> =100mA        | —    | 1.7  | 3.0  | V    |
| Ö                     | Holding Current                                 | Ι <sub>Η</sub>   | —                             | —    | 1.0  | —    | mA   |
| Ш<br>Ц                | Critical Rate of Rise of<br>Off-State Voltage   | dv/dt            | Vin=240Vrms , Ta=85°C (Note3) | —    | 500  | _    | V/µs |
| DE                    | Critical Rate of Rise of<br>Commutating Voltage | dv/dt(c)         | Vin=60Vrms , IT=15mA (Note3)  | —    | 0.2  | _    | V/µs |

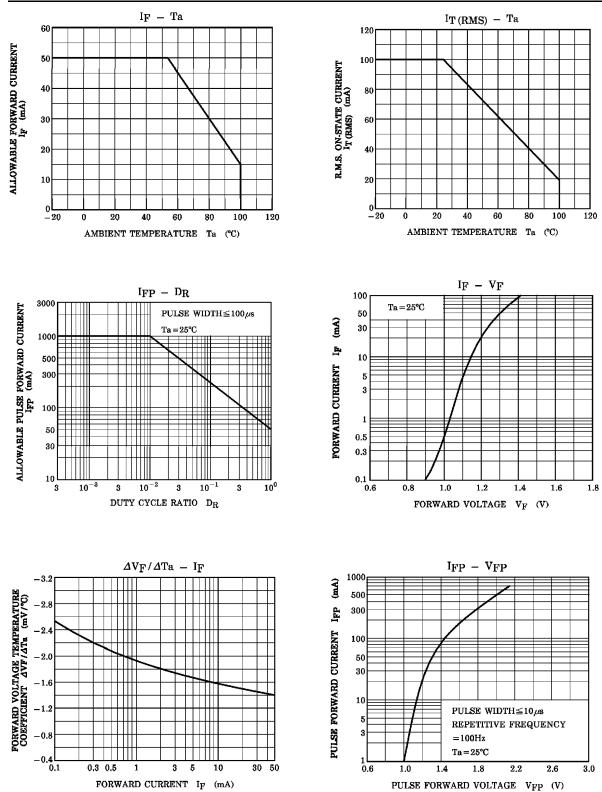
#### COUPLED ELECTRICAL CHARACTERISTICS(Ta=25°C)

| CHARACTERISTIC                | SYMBOL          | TEST CONDITION      | MIN.               | TYP.             | MAX. | UNIT   |
|-------------------------------|-----------------|---------------------|--------------------|------------------|------|--------|
| Trigger LED Current           | I <sub>FT</sub> | V <sub>T</sub> =6V  | —                  | 5                | 10   | mA     |
| Capacitance (Input to Output) | Cs              | VS=0 , f=1MHz       | —                  | 0.8              | _    | pF     |
| Isolation Resistance          | Rs              | VS=500V             | 1×10 <sup>12</sup> | 10 <sup>14</sup> | _    | Ω      |
| Isolation Voltage             | BVs             | AC , 1minute        | 5000               |                  | _    | Vrms   |
|                               |                 | AC , 1second,in oil | —                  | 10000            | _    | VIIIIS |
|                               |                 | DC , 1minute,in oil | _                  | 10000            | _    | Vdc    |

#### (Note 3)dv/dt TEST CIRCUIT



# TOSHIBA



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60

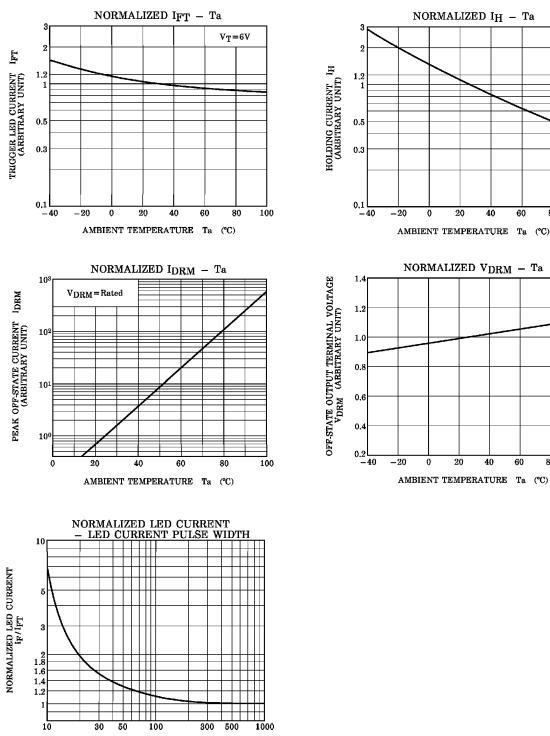
60

80

100

80

100



LED CURRENT PULSE WIDTH  $P_W$  ( $\mu s$ )

#### **RESTRICTIONS ON PRODUCT USE**

000707EBC

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